

SANYO

No. 4867A

STK6712BMK4**Unipolar Fixed-Current Chopper-Type
4-Phase Stepping Motor Driver****Overview**

The STK6712BMK4 is a unipolar fixed-current chopper-type 4-phase stepping motor driver hybrid IC (HIC) which uses a MOSFET power device. The excitation sequence signal is active low.

Applications

- Serial printer, line printer, and laser beam printer (LBP) paper feed and carriage motor drivers
- PPC scanner and LBP paper feed drivers
- XY plotter pen drivers
- Industrial robot applications, etc.

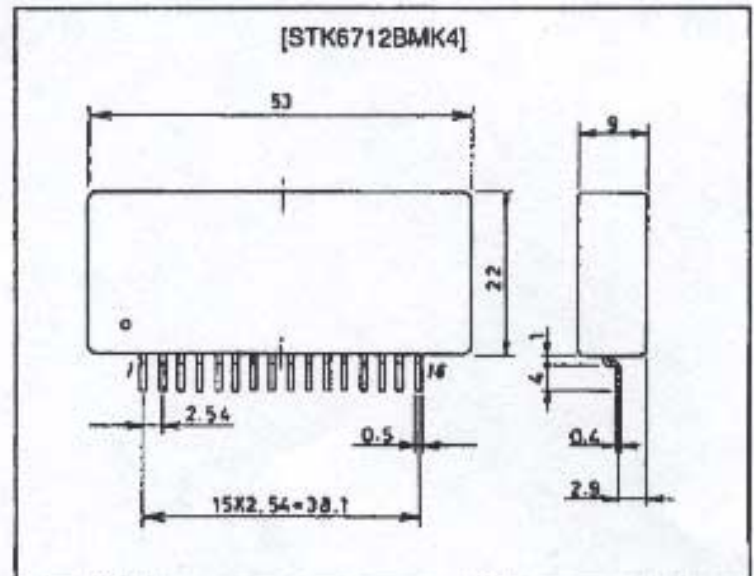
Features

- This IC has the features of the STK6712BMK3, plus a simultaneous input prevention circuit that protects the IC from any malfunction of the excitation signal.
- Self-excitation design means chopping frequency is determined by motor L and R. Supports chopping at 20 kHz or higher.
- Very low number of external components required.
- Wide operating supply voltage range ($V_{CC1} = 18$ to 42V)
- Excitation sequence signal is active low, and is TTL level for direct interfacing to the microcomputer and gate array.
- The unipolar design enables use as a driver for hybrid, PW, or VR type stepping motors.
- Supports W1-2 phase operation, with a dual Vref pin.

Package Dimensions

unit: mm

4129



Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage 1	$V_{CC1\text{ max}}$	No input signal	52	V
Maximum supply voltage 2	$V_{CC2\text{ max}}$	No input signal	7	V
Maximum phase current	$I_{OH\text{ max}}$	per phase, $R/L = 5\ \Omega, 10\text{ mH}, 0.5\text{ s}$ pulse, V_{CC} input	2.5	A
Substrate temperature	$T_c\text{ max}$		105	$^\circ\text{C}$
Junction temperature	$T_J\text{ max}$		150	$^\circ\text{C}$
Storage temperature	T_{sig}		-40 to +125	$^\circ\text{C}$
Repeated avalanche resistance	$E_{ar\text{ max}}$		38	mJ

Allowable Operating Ranges at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V_{CC1}	With input signal	18 to 42	V
Supply voltage 2	V_{CC2}	With input signal	4.75 to 5.25	V
Phase driver voltage resistance	V_{DSS}		(min) 120	V
Phase current	$I_{OH\text{ max}}$	Duty 50%	(max) 1.7	A

Junction Thermal Resistance

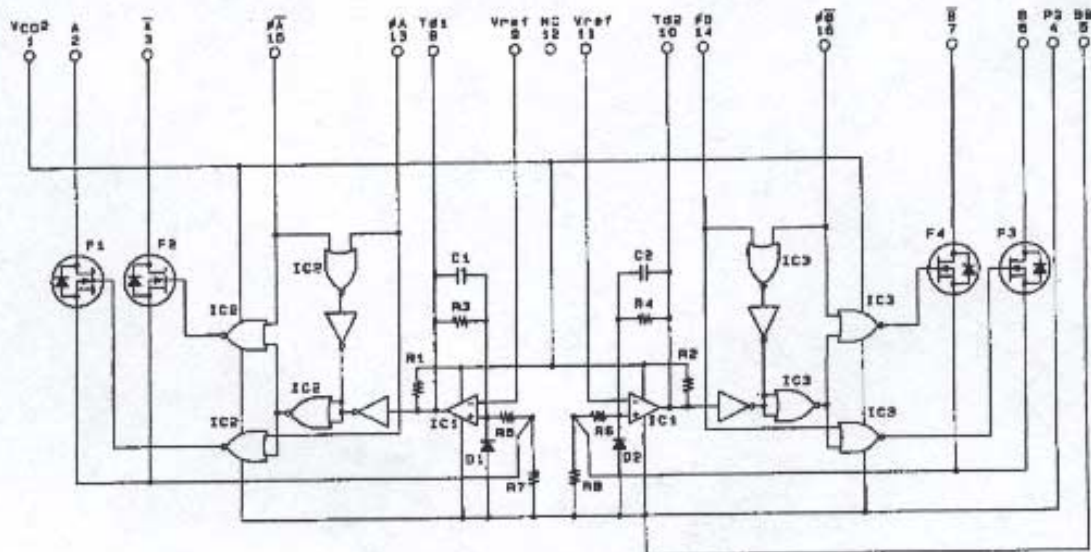
Parameter	Symbol	Conditions	Ratings	Unit
Power FET	θ_{j-c}		13.5	$^\circ\text{C/W}$

Electrical Characteristics at $T_c = 25^\circ\text{C}, V_{CC1} = 36\text{ V}, V_{CC2} = 5\text{ V}$

Parameter	Symbol	Conditions	min	typ	max	Unit
Output saturation voltage	V_{ST}	$R_L = 23\ \Omega, V_{IN} = 0.8\text{ V}$		1.1	1.5	V
Output current (average)	$I_{o\text{ ave}}$	$R/L = 3.5\ \Omega/3.8\text{ mH}, V_{IN} = 0.8\text{ V}$ per phase	0.45	0.50	0.55	A
Pin current dissipation (average)	I_{CC2}	Load, $R = 3.5\ \Omega, L = 3.8\text{ mH}, V_{IN} = 0.8\text{ V}$ per phase		15	25	mA
FET diode voltage	V_{df}	$idf = 1.0\text{ A}$		1.2	1.8	V
TTL input ON voltage	V_{IH}	Input voltage when F1, 2, 3, 4 ON	2.0			V
TTL input OFF voltage	V_{IL}	Input voltage when F1, 2, 3, 4 OFF			0.8	V
Switching time	t_{ON}	$R_L = 24\ \Omega, V_{IN} = 0.8\text{ V}$		100		ns
	t_{OFF}	$R_L = 24\ \Omega, V_{IN} = 0.8\text{ V}$		0.2		μs

Note: With constant voltage power supply.

Internal Equivalent Circuit



448384

